

## Memory Seeds Enable High Structural Phase Purity in 2D Perovskite Films for High-Efficiency Devices

Siraj Sidhik, Wenbin Li, Mohammad Samani, Hao Zhang, Yafei Wang, Justin Hoffman, Austin Fehr, Michael Wong, Claudine Katan, Jacky Even, et al.

### ► To cite this version:

Siraj Sidhik, Wenbin Li, Mohammad Samani, Hao Zhang, Yafei Wang, et al.. Memory Seeds Enable High Structural Phase Purity in 2D Perovskite Films for High-Efficiency Devices. Advanced Materials, 2021, 33 (29), pp.2007176. 10.1002/adma.202007176 . hal-03252788

## HAL Id: hal-03252788 https://hal.science/hal-03252788v1

Submitted on 7 Jul2023

**HAL** is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers. L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

# Memory seeds enable high structural phase purity in 2D perovskite films for high-efficiency devices

3 Siraj Sidhik, Wenbin Li, Mohammad H. K. Samani, Hao Zhang, Yafei Wang, Justin

- 4 Hoffman, Austin K. Fehr, Michael Wong, Claudine Katan, Jacky Even, Amanda B.
- 5 Marciel, Mercouri G. Kanatzidis, Jean-Christophe Blancon<sup>\*</sup> and Aditya D. Mohite<sup>\*</sup>
- 6
- 7 Dr. S. Sidhik, W. Li, M. H. K. Samani, H. Zhang, Y. Wang, A. K. Fehr, M. Wong, A. B. Marciel
- 8 Dr. J.-C. Blancon, Dr. A. D. Mohite Department of Chemical and Biomolecular Engineering,
- 9 Rice University
- 10 Houston, Texas 77005, USA
- 11 Email : <u>blanonjc@gmail.com</u>, <u>adm4@rice.edu</u>
- 12
- 13 W. Li, H. Zhang
- 14 Applied Physics Graduate Program,
- 15 Smalley- Curl Institute
- 16 Rice University
- 17 Houston, Texas, 77005, USA
- 18 J. Hoffman, Prof. M. G. Kanatzidis
- 19 Department of Chemistry and Department of Materials Science and Engineering,
- 20 Northwestern University
- 21 Evanston, Illinois 60208, USA
- 22
- 23 Dr. C. Katan
- 24 Univ Rennes, ENSCR, INSA Rennes, CNRS,
- 25 ISCR (Institut des Sciences Chimiques de Rennes) UMR 6226,
- 26 F-35000 Rennes, France.
- 2728 Prof. J. Even
- 29 Univ Rennes, INSA Rennes, CNRS
- 30 Institut FOTON, UMR 6082
- 31 Rennes F-35000, France
- 32
- 33 Keywords: two- dimensional perovskite, intermediate phase, crystallinity, orientation,
- 34 photostability
- 35
- 36 Two-dimensional (2D) perovskites are a class of halide perovskites offering a pathway for
- 37 realizing efficient and durable optoelectronic devices. However, the broad chemical phase
- 38 space and lack of understanding of film formation have led to quasi-2D perovskite films with
- 39 polydispersity in perovskite layer thicknesses, which have hindered devices performance and

1 stability. Here, we demonstrate a simple and scalable approach termed as the phase-selective 2 method to fabricate 2D perovskite thin-films with high phase purity. The phase-selective 3 method involves dissolution of single-crystalline powders with homogeneous perovskite layer 4 thickness in desired solvents to fabricate thin-films. In-situ characterizations reveal the 5 presence of sub-micron-sized seeds in solution that preserve the memory of the dissolved 6 single-crystals and dictate the nucleation and growth of grains with identical thickness of the 7 perovskite layers in thin-films. Photovoltaic device with a p-i-n architecture were fabricated with such films, which yield an efficiency of 17.1% enabled by an open-circuit voltage of 8 9 1.20V, while preserving 97.5% of their peak-performance after 800 hours under illumination 10 without any external thermal management.

11 Low-dimensional materials have offered tremendous promise due to the novel properties arising 12 from their size and structure. However, preserving their pristine properties when they are solution-13 processed to form thin films or hierarchical assemblies required for applications has been major bottleneck across multiple fields and materials for several decades<sup>[1-6]</sup></sup>. For example, when 14 15 assembled into thin films, the unique properties of low-dimensional materials realized at a single crystal level are overshadowed due to disorder arising from materials polydispersity (heterogeneity 16 in size, structure, and orientation), which results in inefficient charge and energy transport in 17 optoelectronic devices. This is largely because there is a limited understanding of the particle 18 19 growth, crystallization, and solvation dynamics, which dictate long-range ordering and properties 20 of low-dimensional material based thin films. Recently, organic-inorganic 2D perovskites have emerged as a new family of 2D semiconductors with unique and tunable physical properties that 21 can be preserved in bulk single crystals.<sup>[7–15]</sup> However, and despite encouraging proof-of-concept 22 thin-film devices,<sup>[16–22]</sup> polydispersity or mixed crystal phases leads typically to a high density of 23 structural phase impurities in films,<sup>[17,23,24]</sup> which has limited device performance and prevented 24 access to specific 2D physical properties in these films.<sup>[11,15,25]</sup> 25

e with the formula $A'_2A_{n-1}M_nX_{3n+1}$ (where A is a small organic cation,
, and $n$ defines the layer thickness) that are separated one from another
anic cations. <sup>[26,27]</sup> A key challenge is to design a reliable, generally
rocess to synthesize phase-pure 2D perovskite thin-films dominantly
distribution of a single perovskite layer thickness, and with a perovskite
ate between the 2D perovskite $n=1$ and the 3D perovskite limiting
e classical synthesis method typically yields a mixture of <i>n</i> -phase and
nave been recent attempts to realize thin-films with narrow distribution
s by using different solvents and organic additives that control the
Infortunately, these efforts have had limited success, and do not
D perovskites. <sup>[30–33]</sup> Our previously reported hot casting method seems
ty in thin films for a few types of 2D perovskites, yet there is little
mediate chemical steps in the films formation, which has limited the
hod to other 2D perovskites. <sup>[34]</sup> We anticipate that the discovery of a
d to fabricate phase pure 2D perovskite thin films will enable
hat concomitantly exhibit high efficiency, scalability, long-term
ell as pave the path for new types of devices, which exploit the rich
ndeed, studying films that are made of multiple phases frustrates our
operties of the 2D perovskites. However, overcoming this long-standing
ndates a deep understanding of the genesis of phase purity during thin-

1 Here, we report on a phase-selective synthesis method involving a pre-crystallization step 2 of 2D perovskite crystalline powders followed by single-step solution processing, to produce 2D 3 perovskite thin-films principally formed from perovskite layers with a single-valued layer 4 thickness (or *n*-value), with good crystallinity and desired orientation suitable for fabricating 5 optoelectronic devices. Comprehensive in-situ X-ray diffraction and correlated in-situ absorbance 6 measurements with dynamic light scattering (DLS) analysis reveals the exact nature of 2D perovskite film formation where the growth is dominated by the nucleation of 200 nm 7 8 homogeneous *n*-value seeds. Proof-of-concept photovoltaic measurements performed on the 9 phase-pure 2D perovskite films exhibit an efficiency of 17.1%, which arises from an increase in 10 the open circuit voltage (V<sub>OC</sub>) and fill factor (FF) as expected from a film with a homogenous 11 energy landscape (or band-gap).



2 Fig. 1 a) Sketch of the phase-selective synthesis method from this work and the classic synthesis 3 method already reported in the literature. Example of the Ruddlesden-Popper BA<sub>2</sub>MA<sub>2</sub>Pb<sub>3</sub>I<sub>10</sub> 2D perovskites here. Grazing incidence wide-angle x-ray scattering patterns of b) the parent-crystal 4 5 powders, c) the thin films synthetized with the phase-selective method and d) the classically 6 synthetized thin films. Labels indicate the Miller indices of the principal diffraction peaks derived 7 from the simulated diffraction pattern of the thin films with convention and plane directions (see 8 details in Fig. S2 and S3). e) Angular-integrated diffraction patterns of the thin films prepared with 9 the phase-selective and classic synthesis methods, and comparison to the parent-crystals. f) 10 Corresponding optical absorbance spectra. Here, the star and hash symbols identify the n=4 and 11 n=2 impurity phases. g) Optical absorbance spectra of the Ruddlesden-popper thin film n=1-4fabricated by phase selective strategy. Here the star symbol identifies the corresponding n+112 13 impurity phase.

14

1

1

Fig. 1 illustrates the two methods used to fabricate thin films of 2D perovskites – the classical one-2 3 step and our approach termed as "phase-selective" method employed for fabricating thin-films of 4 2D perovskites and the corresponding structural and optical properties of the films. The classic 5 synthesis method involves dissolving (by stirring for 12 hours) precursor materials (for example, 6 PbI<sub>2</sub>, BAI, and MAI, with BA and MA standing for butylammonium and methylammonium, 7 respectively) in stoichiometric proportions corresponding to the desired *n*-value in solution, followed by spin casting on a substrate and annealing at 100°C.<sup>[24]</sup> This approach vields thin-films 8 9 with a mixture of 2D perovskite *n*-phase materials. For example, when precursors are mixed in 10 stoichiometric proportions to fabricate  $BA_2MA_2Pb_3I_{10}$  (*i.e.* Ruddlesden-Popper n=3 2D perovskite), the classic synthesis method produces films composed of a mixture of the n=2, n=3, 11 and n=4 2D perovskite phases and often with evidences of the 3D halide perovskites.<sup>[24,35]</sup> These 12 13 films are often referred to as quasi-2D and denoted as < n >= 3 films. In order to promote phase 14 selectivity during thin-film formation, we added an extra step in the synthesis protocol. First, we 15 slowly crystallized 2D perovskite single crystal powders (micrometer to millimeter sizes) of a desired *n*-value from the precursor materials hereafter termed as parent-crystals (Fig. 1a).<sup>[26,27]</sup> 16 17 These parent crystals exhibited a high degree of phase purity, typically around 90 to 95% as 18 validated using x-ray powder diffraction measurements. As illustrated in Fig. 1b for the 19  $BA_2MA_2Pb_3I_{10}$  parent-crystal powders, the diffraction signal stems predominantly from the n=3phase with less than 10 % of *n*=4 impurities. These parent-crystals were then dissolved by heating 20 21 at 70 °C in the optimized solvent for 6 or more hours and the resulting solution was spin casted and 22 annealed.

After optimization of the solvent composition (5 wt% MACl with the 2D single-crystal powder in 1 DMF for the Ruddlesden-Popper  $BA_2MA_2Pb_3I_{10}$  and dissolution process (Fig. S1), we 2 3 synthesized thin-films, which exhibited a narrow variation of phase distribution in comparison to 4 the classical method as verified by grazing incidence wide-angle x-ray scattering (GIWAXS) and 5 absorption spectroscopy. The GIWAXS pattern of the n=3 Ruddlesden-Popper 2D perovskite 6 films synthesized with the phase-selective method is shown in Fig. 1c. A spot-like diffraction 7 pattern indicates higher crystallinity than the films fabricated using the classical method as shown 8 in Fig. 1d. The experimental GIWAXS pattern was accurately reproduced and the diffraction peaks 9 indexed from the 2D perovskite single crystal structure with vertically oriented perovskite layers 10 (see the illustration of the structure and details of the analysis in the Fig. S2 and S3). The degree 11 of phase purity observed in oriented films (Fig. 1c) was also confirmed by abrasing the thin films 12 (see details in Fig. S4) and measuring the XRD pattern of the powder. In contrast to the results 13 obtained in Fig. 1c using the phase selective method, similar measurements on the films produced 14 using the classical method (Fig. 1d) resulted in mixed phases of 2D perovskite with high *n*-value 15 and 3D perovskites, which exhibited a lower degree of crystallinity and non-preferential orientation of the perovskite layers (more ring-like pattern).<sup>[36]</sup> Fig. 1e shows the integrated 16 17 diffraction intensity over all azimuthal directions of the GIWAXS patterns for the thin-films 18 produced using the phase-selective and the classical method, which are both compared with the 19 pattern of the parent single-crystal powders (grey curve). The phase mixing is clearly observed by 20 the mismatch of several diffraction peaks in the classic thin films as compared to the diffraction of the parent crystals. Complimentary to the GIWAXS line cuts, we also measured the absorbance 21 22 spectra of the thin-films using the two methods. The analysis of the results from GIWAXS and 23 absorbance yields a phase purity of about 90% for the  $BA_2MA_2Pb_3I_{10}$  films. One the other hand,

we estimated a distribution of *n*=3 and *n*=2 phases in equal quantity, as well as the presence of *n*=4 and phases with higher *n*-value or 3D-like perovskite (blue dashed curve in Fig. 1e, f) in the classic thin films. We note that the small values of absorbance below 1.8 eV indicates a negligible amount of high *n*-value crystal phases or 3D-like perovskite in our films, and we attribute this small absorption to previously observed surface states resulting from the local distortions observed in the GIWAXS data.<sup>[37-39]</sup>

7 Next, we verified the applicability of the phase selective approach to thin films of 8 Ruddlesden-popper with different *n* thicknesses (n=1, 2, 4). Based on the optical absorbance of 9 the films, we infer a phase purity 90%) of the desired n value with a few percentages of n+110 impurities and negligible amount of higher *n*-value crystal phases or 3D (see Fig. 1g). Using the 11 Debye Scherrer analysis on the (111) diffraction peak (Fig. S5), we extracted an average size of 12 31 nm for the thin films. These values are comparable to those of the parent-crystals (average 13 grain-size 64 nm), thus confirming that the crystalline quality is well preserved in the thin films 14 made using the phase-selective method. To further check if our synthesis approach is applicable 15 to 2D perovskite crystals with other compositions and structures, we performed measurements on 16 the Dion Jacobson n=3 2D perovskite thin films (4AMP-MA<sub>2</sub>Pb<sub>3</sub>I<sub>10</sub> where 4AMP is 4- Amino 17 methyl piperidine, Fig. S6-S8), which also demonstrated results consistent with those obtained for 18 Ruddlesden-Popper thin-films.



**Fig. 2** a, b) Evolution of the x-ray diffraction during film formation and comparison between our phase-selective synthesis method and the classic one. All peaks were identified to a 2D perovskite phase of defined *n*-value (or perovskite layer thickness), except for one peak assigned to the presence of an intermediate complex in solution. c, d) Corresponding evolution of the ratio of each phase relative to the fully integrated diffraction. e, f) Evolution of the optical absorbance spectra of the films during synthesis. Each peak in the spectra correspond to the ground exciton transition of a given perovskite layer thickness.

9

10 The significant differences in the degree of phase purity and crystal orientation observed between

11 the thin-films synthesized with the phase-selective and the classical method imply that the method

of preparation of the precursor solutions before casting significantly affects the kinetics of 1 2 formation of the 2D perovskite thin-films. For the classic synthesis method, Quintero-Bermudez et al.<sup>[24]</sup> proposed a kinetic model showing that intermediate solvent complexes provide a 3 4 framework for nucleation of the 2D perovskite layers during the annealing process. However, there 5 has been no prior report on understanding the mechanism that leads to phase pure 2D perovskite 6 films using the phase-selective method. Therefore, in order to understand the differences in the 7 crystallization kinetics and film formation between the two synthesis methods we performed in-8 situ x-ray diffraction and absorbance of the thin-films during its growth, as illustrated in Fig. 2, 9 which has shown to be a powerful approach for identifying the chemical origin of the different phases (n values) during the thin-film formation.<sup>[24]</sup> These experiments were performed by spin 10 11 casting the respective precursor solution on a glass microscope slide, which was kept at room 12 temperature without annealing in order to slow down the kinetics of nucleation and film formation. 13 We note that this process also yielded films like those obtained by post annealing (Fig. S9). Fig. 14 2a and 2b illustrate the evolution of the diffraction pattern as a function of time from the moment 15 the precursor solutions were spin casted up to eighty minutes of continuous monitoring of the x-16 ray diffraction pattern. The signature diffraction peaks of each 2D perovskite phase were identified 17 and monitored as a function of time with respect to the total diffraction of the sample (Fig. 2c, d). Both methods showed diffraction at about q=1 Å<sup>-1</sup> after one minute, indicative of the formation of 18 19 the halide perovskite film, and after a few minutes most of the solution nucleated and formed 2D perovskite phases. We also observed a weak diffraction peak in the classic method around 0.57  $Å^{-}$ 20 <sup>1</sup>, which indicates the presence of intermediate phase complexes in the excess solution.<sup>[24]</sup> Recent 21 22 work on the classical synthesis method has demonstrated the existence of an intermediate gel phase during growth.<sup>[40]</sup> This gel phase was identified as one of the processes that hinders the formation 23

of homogenous 2D perovskite thin films. For film growths using the phase-selective method, the 1 targeted *n*=3 2D perovskite phase formed relatively more quickly and continued growing over time 2 as the amount of excess solution is consumed (Fig. 2a, 2c). Based on these data, we infer that the 3 4 phase-selective synthesis method bypasses the intermediate phase (absence of diffraction peak 5 corresponding to intermediate phase complex), which promotes the formation of the desired layer 6 thickness with negligible phase segregation. The absence of intermediate phase in the phase 7 selective method is the result of poor interaction between the solvent and the undissolved seeds. 8 Hence, the film growth is solvent independent when compared to the classic method where the 9 evaporation of the solvents leads to the film formation process.

10 In order to verify the different phases of thin-film formation, we also performed in-situ optical 11 absorbance measurements as illustrated Fig. 2e, which corroborated that after a couple of minutes 12 the solution nucleates dominantly into the n=3 2D perovskite phase. The excess solution, which is 13 not consumed initially, allows for further improvement of the purity of the n=3 phase at the 14 expense of the *n*=4. The *n*=4 impurity phase decreased to a few percent after tens of minutes, as 15 confirmed by both x-ray diffraction and absorbance data (Fig. 2a, c, e). On the other hand, analysis 16 of the film formation in the classic synthesis method yields a mixture of n=1 and n=2 phases after 17 a few minutes of nucleation (Fig. 2b, d, f). Subsequently, we observed the formation of the n=318 2D perovskite phase over a period of tens of minutes, accompanied by the dissolution of the *n*=1 19 2D perovskite crystals. The final film from the classic method at the end of our experiment was composed of a mixture of n=2 and n=3 2D perovskites with little excess solution remaining. These 20 21 in-situ experiments emphasize the important differences in film formation between the phase-22 selective method and the classic one. First, we note that in the phase-selective method, the desired 23 2D perovskites phase (n=3) is readily formed as the dominant phase from the initial nucleation of

the solution. In contrast, the classical method initially yields phases with lower *n* value, followed by a subsequent slow growth of the expected phase.<sup>[41,42]</sup> Second, the rate of nucleation is significantly faster in the phase-selective method compared to the classic approach, as validated from the absorbance data. These observations suggest that despite their apparently identical clear yellow colour and similar viscosity (Fig. S10), there exist significant differences in the solvation dynamics (precursor-solvent interactions) and the chemical origin of the two precursor solutions prepared for each synthesis method.



https://doi.org/10.1002/adma.202007176 Sidhik S et al. Adv. Mater. 33, 29, 2007176 (2021)

1

**Fig. 3** a) Optical absorbance of the precursor solutions obtained before spin coating and annealing. The gray region corresponds to the absorption of PbI<sub>2</sub>. b) Correlation function versus delay time derived from dynamic light scattering performed on the precursor solutions. c) Statistical distribution of the particle size in solution and comparison between our phase-selective synthesis method and the classic one. d) Correlation function versus delay time derived from dynamic light scattering performed for different concentration of the perovskite solution for the phase-selective method. Dashed lines are fit to the data. Gray and orange regions indicate small and large particle

size in solution, respectively, e) Correlation function versus delay time derived from dynamic light
scattering performed on the MAPbI<sub>3</sub> solution obtained by dissolving the synthesized crystals in
the solvent, f-g) In-situ visualization of the formation of grains in 2D perovskite thin films and
comparison between the phase-selective synthesis method and the classic one, h) .

5

6 In order to elucidate the underlying mechanism that results in phase-pure films using the 7 phase-selective method (Fig. 1), we investigated the composition of the precursor solution using 8 correlated absorbance and dynamic light scattering measurements (Fig. 3). Fig. 3a shows the 9 optical absorbance as a function of excitation energy for the precursor solutions prepared using 10 both the classical and phase-selective methods. The absorbance spectra measured for the solutions 11 prepared using the classical method showed an absorbance edge of 2.4 eV (black curve in Fig. 3a) 12 independent of the stoichiometry of the solution (n=1, 2, 3 and 4). The optical absorbance spectra is consistent with that obtained for PbI<sub>2</sub> ions in solution, also in agreement with the recent report 13 of Quintero-Bermudez and co-workers.<sup>[24]</sup> On the other hand, the precursor solutions prepared 14 15 using the phase-selective method yield, in addition to the PbI<sub>2</sub> absorbance, an absorbance edge 16 varying from 2.1 eV for n=2, to 2.0 eV for n=3, and to 1.85 eV for n=4. These values match very well the optical bandgap energy observed in the corresponding parent single-crystals<sup>[43]</sup>. Since the 17 absorption edge for the n=1 2D perovskite solution overlaps with the absorbance of the PbI<sub>2</sub>, we 18 were unable to resolve it from the solution. These absorbance measurements imply that there is a 19 20 clear difference in chemical species for the precursor solutions prepared using the classical and 21 phase-selective method.

Next, we used DLS to probe the size distribution of the chemical species in the precursor solutions. Fig. 3b shows the correlation versus time for both the classical and phase selective methods. The solutions prepared using the classical method showed a mono-modal distribution (single exponential), which when fitted using a single decay model (see details in method section

of the SI) vielded an average particle size of  $\sim 1$  nm. The latter is in close agreement with the PbI<sub>2</sub> 1 bond length of 0.7 nm. Therefore, based on the DLS results and the absorbance spectra, we 2 3 attribute this to the presence of PbI<sub>2</sub> ions in chemical equilibrium with the solvent. On the other 4 hand, the DLS measurements performed on the solution prepared using the phase selective method 5 revealed a bimodal distribution with one similar to the classical solution with <1 nm sized particle 6 and a much larger size distribution with an average particle size ~200 nm (red curve, Fig. 3b). 7 These correlated DLS and the absorbance measurements presented in the previous paragraph 8 unambiguously confirmed the presence of undissolved seeds in solution with the chemical makeup 9 of the parent crystal dissolved for making the solution, hence termed as memory seeds.

10 We infer that these seeds remain in chemical equilibrium with the solvent for a given 11 concentration. To verify this, we varied the dilution level (from 0.4M to 0.1M) of 2D perovskite 12 crystal solution, and found a critical point (0.2 M) at which the bimodal correlation (indicative of 13 the presence of the large sized memory seeds) changes to a unimodal correlation (similar to the precursor solution prepared using classical method), Fig. 3d. This can be attributed to the 14 15 disruption of the chemical equilibrium between the seed and the solvent. Therefore, based on the 16 dilution experiments and the absorbance data, suggests that the detected large seeds are indeed a 17 remnant of the n=3 phase of the parent-crystals dissolved in solution. We note that the approach 18 of dissolving single-crystalline powders in solution has been previously tested for fabricating 3D perovskite thin films with better morphology and enhanced crystalline quality.<sup>[44,45]</sup> As a control 19 20 experiment, we also performed a correlated dynamic light scattering and absorption measurements 21 on the MAPbI<sub>3</sub> solution obtained by dissolving parent crystals. We obtained a typical size of 22 approximately 1 nm (see Fig. 3e) and absorption corresponding to PbI<sub>2</sub> (see Fig. S12), which is

fundamentally different from the phase selective solution obtained by dissolving the 2D
 perovskites.

3 The next logical step towards understanding the mechanism of film formation was to directly 4 image the precursor solutions during the formation of 2D perovskite thin-films (Fig. 3f, g) using 5 in-situ high-resolution microscopy. We noticed striking differences in the nucleation and grain 6 formation between the two synthesis protocols. In the case of the classic method, we observed a 7 random nucleation of 2D perovskite grains with filament-like morphology, which grow to form 8 the film (Fig. 3g). On the other hand, in the phase-selective method each grain nucleated at a single 9 location from the undissolved seed and grew radially outward and independently from the other 10 grains (Fig. 3f). These grain boundaries are formed when either two grains coalesced during the 11 growth or all reactants in solution are consumed and the growth terminates. From the scaled down in-situ microscopic image shown in Fig. 3f, we estimate a concentration of less than 10<sup>-10</sup> M of 12 13 active seeds in the precursor solution. The observation of nucleation and grain growth using the 14 two protocols was captured in movies (Supplementary Movie 1 and Movie 2) and is depicted 15 schematically in Fig. 3h. The films synthesized with the phase-selective method featured relatively 16 large (micron size) and ordered grains, whereas the classic method yielded disordered wire-like 17 morphology (Fig. 3f, g, right side images, and confirmed by characterization of the surface 18 morphology of post annealed films in Fig. S13). We note that although we use the same time scale 19 in Fig. 3f and 3g, the resulting macroscopic growth of the films was in fact faster using the phase-20 selective method as observed during the in-situ experiments in Fig. 2. Here, we observe a large 21 number of grains nucleated simultaneously in the phase-selective growth, whereas in the classic 22 synthesis method, the film growth was slower and occurred at the interfaces between nucleated 23 crystals and solution. These results further corroborate the inferences from the absorbance and

DLS experiments, that the precursor solutions in the phase-selective method contain a low-density of undissolved seeds for the nucleation of 2D perovskite grains as illustrated in the schematic of Fig. 1a. In addition, consistent with the analysis of the in-situ experiments in Fig. 2, they show that the seeds in solution retain the memory of the phase of the 2D perovskite parent-crystals, which were dissolved to form the precursor solution for film growth in the phase-selective synthesis method.

7 Based on the measurements described in Fig. 2 and Fig. 3, we develop a model as illustrated 8 in Fig. 3h, which depicts the mechanism of film formation in both types of synthesis methods. In 9 the classical method, the nucleation initiates at the air-liquid interface and the nucleation front sweeps across the film as discussed in previous work<sup>[46,47]</sup>. In comparison, the phase-selective 10 11 method the nucleation takes place preferentially at the memory seeds that create grains with high 12 phase purity as imaged using the microscopy (see Fig. 3f). More recently it was claimed that colloids identified as  $MA^+/PbI_x$  complexes promote the nucleation of mixed *n*-phase in 2D 13 perovskite films.<sup>[32]</sup> The needle-shaped crystal film morphology reflects the initial formation of 14 15 solvated intermediates phases such as the one-dimensional non-perovskite (CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>·DMF) as has been recognized in MAPbI<sub>3</sub> film growth previously.<sup>[48]</sup> Then the final phase(s) form by 16 17 subsequent reactions that accomplish the conversion. The phase-selective method avoids these 18 solvated intermediates as the existing seeds act to grow the correct 2D phase. It is therefore 19 apparent that the two different methods have very different starting points and end up at very different destinations during the film formation process, with the phase-selective method affording 20 21 purer single-phase 2D films. Another advantage of the phase-selective method is that it facilitates 22 a single step thin film deposition due to solvent independent seed assisted growth, thereby 23 significantly improving film reproducibility critical for scaling-up in comparison to other

deposition strategies like anti-solvent, hot casting, and sequential deposition.<sup>[24,32,49]</sup> In addition,
the concentration of the solvent can be tuned in the phase-selective method to achieve different
size of the memory seeds and achieve solvent independent phase selective growth adapted to user's
requirements (see Fig. S1, S3 and 3d).



5

6 Fig. 4 a) Schematics of the solar cell devices where HTL and ETL stand for the hole and electron 7 transporting layers. b) Current-voltage characteristics of the cells using the n=3 thin films of Ruddlesden-Popper (BA) and Dion Jacobson (3AMP) prepared with the phase-selective method. 8 9 The HTL is PEDOT: PSS in this case. c) Current-voltage characteristics of our champion solar 10 cells using 2D perovskite thin films of Ruddlesden-Popper (BA) with n=3 and n=4, and Dion Jacobson (3AMP) with *n*=4 synthetized with the phase-selective method. The HTL is NiOx here. 11 12 Light-colored curves correspond to reverse voltage bias scans. d) Statistical distribution of the 13 figures of merit of the n=4 2D perovskite solar cells shown in c, e) Statistical distribution of the 14 stability data obtained by measuring four devices with an average efficiency (16.0±0.98%) for the

phase selective method from the same batch, for a Ruddlesden-Popper (BA) with n=4 solar cell under constant 1-Sun illumination and  $60\pm5$  %RH compared to the stability measured in a reference thin film solar cell with average efficiency (10.58±1.4%) fabricated with the classic method.

5

6 To illustrate the impact of phase purity of the 2D perovskite thin-films in devices, we fabricated 7 p-i-n junction planar solar cells using the standard ITO/HTL/2D-Perovskite/ETL/Al architecture 8 (see Fig. 4a). The ETL used was PCBM and two HTLs - PEDOT: PSS and NiO were used. Solar 9 cells based on the Ruddlesden-Popper BA<sub>2</sub>MA<sub>2</sub>Pb<sub>3</sub>I<sub>10</sub> (n=3) films prepared with the phase-10 selective method yielded a peak power conversion efficiency (PCE) of 12.60% with a  $V_{OC}$ = 1.1 V,  $J_{SC}$  = 14.0 mA.cm<sup>-2</sup>, and fill factor (FF) of 83% with negligible hysteresis (Fig. 4b). We also tested 11 12 photovoltaic devices fabricated using Dion Jacobson 4AMP-MA<sub>2</sub>Pb<sub>3</sub>I<sub>10</sub> films, which exhibited a peak PCE of 11.40% and at least 3% higher than our previous result<sup>[34]</sup>. However, it has been well 13 14 established that the PCE with PEDOT:PSS as the HTL has been limited by the energy band alignment<sup>[50]</sup>. 15

16 Therefore, with the goal of improving the efficiency, we fabricated photovoltaic devices using 17  $BA_2MA_2Pb_3I_{10}$  (n=3),  $BA_2MA_3Pb_4I_{13}$  (n=4),  $4AMP-MA_3Pb_4I_{13}$  (n=4) phase pure 2D perovskite with NiO as the HTL (Fig. 4c). The champion device was obtained using a BA<sub>2</sub>MA<sub>3</sub>Pb<sub>4</sub>I<sub>13</sub> film, 18 which showed a  $J_{SC}$ =17.56 mA.cm<sup>-2</sup>,  $V_{OC}$ =1.20 V, fill factor 81.1%, and power conversion 19 20 efficiency 17.1 %, with negligible hysteresis. The stabilized efficiency of 17.0% measured at the 21 maximum power point ( $V_{0C}$ = 0.99V) is depicted in Fig. S14. The highest efficiency device using 22 the Dion-Jacobson 4AMP-MA<sub>3</sub>Pb<sub>4</sub>I<sub>13</sub> film and BA<sub>2</sub>MA<sub>2</sub>Pb<sub>3</sub>I<sub>10</sub> (n=3) was 15.7%, and 14.3% 23 respectively. The statistics over tens of BA<sub>2</sub>MA<sub>3</sub>Pb<sub>4</sub>I<sub>13</sub> and 4AMP-MA<sub>3</sub>Pb<sub>4</sub>I<sub>13</sub> devices presented in Fig. 4d confirm the reproducibility of the solar cell performances and clearly demonstrate that 24 25 the phase-selective method used to synthesize the 2D perovskite thin films yields large open-circuit

voltage and fill-factor. The external quantum efficiency (EQE) and the integrated current density 1 2 for the Ruddlesden-popper (n=3, and n=4) 2D perovskite solar cells is depicted in Fig. S15. The 3 average EOE is in good agreement with the current density obtained from the J-V characteristics 4 with <5% difference in the J<sub>SC</sub> arising from a spectral mismatch between two sources. Importantly, 5 the contribution to the EQE from the impure phases was  $\sim 9\%$  of the J<sub>SC</sub> consistent with our 6 absorbance and GIWAX measurements in Fig. 1e and 1f. In order to understand the differences 7 in the device performance between the classical and phase selective method, we fabricated solar 8 cells using  $BA_2MA_2Pb_3I_{10}$  (*n*=3),  $BA_2MA_3Pb_4I_{13}$  (*n*=4) using classical method (see Fig. S16). The 9 champion device using the classical method with a stoichiometric precursor composition for 10  $BA_2MA_2Pb_3I_{10}$  (n=3) and  $BA_2MA_3Pb_4I_{13}$  (n=4) resulted in a PCE of 9.3% and 11.0% respectively 11 (see S16C for statistics). The photovoltaic parameters of the  $BA_2MA_2Pb_3I_{10}$  (n=3), and 12 BA<sub>2</sub>MA<sub>3</sub>Pb<sub>4</sub>I<sub>13</sub> (*n*=4) 2D perovskite solar cells fabricated using the phase-selective and classical 13 method is tabulated in Table S1.

14 The values obtained for the power conversion efficiency are among the best compared to previous results based on <n> quasi-2D perovskite solar cells.<sup>[18,22,42,51–55]</sup> We note that although 15 16 the use of quasi-2D perovskite films is beneficial for achieving current densities larger than 20  $mA.cm^{-2}$  as compared to about 17 mA.cm<sup>-2</sup> here with high phase purity films, it actually limits the 17 18 Voc and FF. The use of quasi-2D perovskite films indeed allows enhancing near-infrared 19 absorption as compared to the lower values observed in high phase purity films (Fig. 1g and Fig. 20 S15) and achieves a balance between photoexcited electron-hole pair (or exciton) dissociation and 21 material stability, however recent studies have demonstrated that a combination of the device field 22 and low-density surface states can efficiently achieve exciton dissociation in 2D perovskite phases with low *n*-value.<sup>[25,37,56]</sup> By achieving high phase purity with the phase-selective method, 2D 23

perovskite thin films naturally exhibit less structural defects, related to the polydispersity of
 classical films, which for example might result in stacking faults and dangling bonds between two
 adjacent layers of different thickness.<sup>[24,35,38]</sup>

4 The superior phase purity of our 2D perovskite films is expected to benefit device stability 5 and to test this hypothesis, we performed stability measurements during operation of our 6 BA<sub>2</sub>MA<sub>3</sub>Pb<sub>4</sub>I<sub>13</sub> solar cell devices. The cells were encapsulated and subjected to a constant 1-Sun 7 illumination for up to 800 hours – under  $60\pm5$  % relative humidity in air (Fig. 4e). The solar cells exhibit no "burn-in" effect<sup>[57]</sup> and lost less than 3% of their initial performances over 800 hours as 8 9 measured using a standard AM 1.5G source. On the contrary, our control solar cell prepared with 10 the classic synthesis method shows a burn-in effect and started to degrade after 200 hours. To the 11 best of our knowledge, these stability results are better than state-of-art 2D perovskite devices with similar performances.<sup>[22,51,53]</sup> These results pave a path for achieving dominantly phase pure thin-12 13 films of 2D perovskites for realizing scalable, high-efficiency devices with long-term stability.

In summary, we developed a phase-selective synthesis method for fabricating 2D perovskite thin films with high phase purity, enhanced crystallinity and desired out-of-plane orientation. The *in-situ* characterization indicates the absence of an intermediate phase complex and reveals a seed assisted nucleation and film growth process. The presence of these sub-micron-sized seeds in the solution which preserves the memory of the dissolved single-crystals was verified. The films fabricated by this method resulted in photovoltaic devices with an efficiency of 17.1%, and enhanced stability.

#### 21 Experimental section

22 *2D perovskite parent crystal synthesis.* The 2D perovskite parent crystals were synthesized by 23 mixing PbI<sub>2</sub>, MACl, and BAI (or 4AMPI in the case of the Dion Jacobson 2D perovskite) in 24 appropriate ratios and dissolving these precursor materials in a mixture of HI/ H<sub>3</sub>PO<sub>2</sub> according to

our previous reports.<sup>[[26,27]]</sup> The solution was stirred at high temperature (>190°C) until all the
 precursors were dissolved, then allowed to cool down to room temperature during which time
 crystals are formed. The crystallized 2D perovskite powder was separated, dried, and characterized
 using x-ray diffraction and absorption.

5 2D perovskite thin film synthesis. For the classic method, the precursors, BAI, MAI, and PbI<sub>2</sub> in 6 appropriate ratios (with 5% of MACl additive) were dissolved in N, N dimethylformamide (DMF). 7 The solution was stirred overnight in an argon filled glove box. Then, the precursor solution was 8 spin coated on the substrates and annealed at  $100^{\circ}$ C on a hot plate. In the phase-selective method, 9 the parent crystals were dissolved in DMF with an addition of 5% MACl. After stirring the solution 10 for at least 6 h, it was spin casted on the substrates followed by annealing at 100°C on a hot plate. 11 Detailed fabrication and solvent optimization techniques are presented in the method section of 12 the Supplementary information.

*In-situ X-Ray diffraction and absorption measurements.* The precursor solutions were spin coated on glass substrates to obtain wet films and the samples were immediately transferred to the x-ray diffraction apparatus for measurements. The area of the diffraction peaks were monitored over time until the 2D perovskite films were fully formed. The same approach was used to probe the evolution of the optical density of the films during formation.

18 *GIWAXS measurement and analysis.* The GIWAXS patterns were measured at the Advanced 19 Photon Source (8-ID-E) and the National Synchrotron Light Source-II (11-BM). At the beamline 20 8-ID-E, the 2D perovskite parent crystals and thin film samples were placed on a Linkam grazing 21 incidence x-ray-scattering stage (temperature at 25°C) inside a vacuum chamber ( $10^{-4}$  torr) with 22 the sample 228 mm away from a Pilatus 1M. The photon energy was 10.91 keV, and the beam 23 size was 200 µm × 20 µm (H × V). At the beamline 11-BM, the samples were measured inside a

vacuum chamber (10<sup>-2</sup> torr) with the sample 267mm away from a Pilatus 800K. The photon energy
was 13.5 keV, and the beam size was 200 µm × 50 µm (H × V). All GIWAXS patterns were taken
at 0.15° incident angle with typically 5 second exposure. The GIWAXS patterns were analyzed
using the GIXSGUI package and Single Crystal-Crystal Maker software.<sup>[58]</sup> *In-situ microscopic imaging*. Few microliters of the precursor solutions were drop casted on a thin

microscopic slide that was then placed in a Titan microscope. The thin film formation without
annealing was imaged using an oil immersion 100X objective over time by taking continuous
snapshot images every second.

9 *Dynamic light scattering measurements*. The precursor solutions were loaded into cylindrical glass 10 cuvettes and the DLS correlation curves were collected at different angle with respect to the 11 incident laser beam. The data were fitted using a single- or bi-exponential decay model to extract 12 the size of the particles in the solution (see details in the method section of the Supplementary 13 information).

14 Solar cell device fabrication. ITO glasses were cleaned by ultra-sonication in soap water, distilled 15 water, acetone, acetone/ethanol (50:50) and isopropyl alcohol for 15 min each, followed by UV 16 treatment for 30 minutes. A thin layer of PEDOT: PSS or NiOx was spin-coated on the ITO 17 substrates at 5,000 rpm for 30 seconds to form the hole-transporting layer. The coated substrates 18 were then transferred to an argon-filled glovebox where the 2D perovskite thin films were 19 synthetized by spin coating and annealing at 100°C for 10 min. The assemblies were completed by 20 spin-coating (at 1,000 rpm for 300 seconds) a thin layer of PCBM (electron-transporting layer) and depositing on top aluminum contacts using a thermal evaporator with a shadow mask having 21 a working area of 31.4 mm<sup>2</sup>. 22

1 Solar cell Characterization. The solar cells were characterized by measuring the current-voltage 2 curves while the cells are exposed to the light from a Newport ABB solar simulator (AM 1.5 G 3 light). The external quantum efficiencies were collected by illuminating the device using the 4 monochromatic light obtained from a quartz-tungsten-halogen source modulated at 2 kHz. The 5 obtained photocurrent was measured by a lock-in amplifier. For stability measurements, the 6 perovskite devices were encapsulated with a UV- curable epoxy and tested under open-circuit 7 conditions, under full-spectrum simulated AM 1.5G in air using the same ABB solar simulator 8 (following the ISOS-L protocol). The relative humidity was measured to be constant at 60±5 %RH. 9 **Supporting Information** 10 Supporting Information is available from the Wiley Online Library or from the author. 11 12 Acknowledgements 13 The work at Rice University was supported by the DOE-EERE 2022-1652 program. J.E. 14 acknowledges the financial support from the Institut Universitaire de France. This work was 15 supported by the Office of Naval Research (ONR) under grant N00014-20-1-2725. This research 16 used facilities of the Advanced Photon Source, a U.S Department of Energy (DOE) Office of 17 Science User Facility operated for the DOE Office of Science by Argonne National Laboratory 18 under Contrast No. DE- AC02- 06CH11357. This research used the beamline 11-BM of the 19 National Synchrotron Light Source II, a U.S. Department of Energy (DOE) Office of Science user 20 facility operated for the DOE Office of Science by Brookhaven National Laboratory under 21 Contract No. DE-SC0012704. W. Li, and M. H. K. Samani contributed equally to this work. 22 23 **Competing interests:** The authors declare no competing interests.

24

25 References

- 1 [1] M. Majidian, C. Grimaldi, L. Forró, A. Magrez, Sci. Rep. 2017, 7, 1.
- [2] B. Sun, M. Vafaie, L. Levina, M. Wei, Y. Dong, Y. Gao, H. T. Kung, M. Biondi, A. H.
  Proppe, B. Chen, *Nano Lett.* 2020, 20, 3694.
- [3] H. Wang, Z. Zeng, P. Xu, L. Li, G. Zeng, R. Xiao, Z. Tang, D. Huang, L. Tang, C. Lai, *Chem. Soc. Rev.* 2019, 48, 488.
- [4] N. Wang, L. Cheng, R. Ge, S. Zhang, Y. Miao, W. Zou, C. Yi, Y. Sun, Y. Cao, R. Yang, *Nat. Photonics* 2016, *10*, 699.
- 8 [5] D. Zhitomirsky, I. J. Kramer, A. J. Labelle, A. Fischer, R. Debnath, J. Pan, O. M. Bakr, E. H.
  9 Sargent, *Nano Lett.* 2012, *12*, 1007.
- [6] M. S. Arnold, J. L. Blackburn, J. J. Crochet, S. K. Doorn, J. G. Duque, A. Mohite, H. Telg,
   *Phys. Chem. Chem. Phys.* 2013, 15, 14896.
- 12 [7] T. Ishihara, J. Takahashi, T. Goto, *Phys. Rev. B* 1990, *42*, 11099.
- 13 [8] D. B. Mitzi, C. A. Feild, W. T. A. Harrison, A. M. Guloy, *Nature* 1994, 369, 467.
- 14 [9] G. C. Papavassiliou, I. B. Koutselas, Synth. Met. 1995, 71, 1713.
- 15 [10] B. Saparov, D. B. Mitzi, Chem. Rev. 2016, 116, 4558.
- 16 [11] L. Mao, C. C. Stoumpos, M. G. Kanatzidis, J. Am. Chem. Soc. 2019, 141, 1171.
- [12] J.-C. Blancon, A. V. Stier, H. Tsai, W. Nie, C. C. Stoumpos, B. Traoré, L. Pedesseau, M. Kepenekian, F. Katsutani, G. T. Noe, J. Kono, S. Tretiak, S. A. Crooker, C. Katan, M. G. Kanatzidis, J. J. Crochet, J. Even, A. D. Mohite, *Nat. Commun.* 2018, *9*, 2254.
- [13] X. Gong, O. Voznyy, A. Jain, W. Liu, R. Sabatini, Z. Piontkowski, G. Walters, G. Bappi, S.
   Nokhrin, O. Bushuyev, M. Yuan, R. Comin, D. McCamant, S. O. Kelley, E. H. Sargent, *Nat. Mater.* 2018, 17, 550.
- [14] G. Long, R. Sabatini, M. I. Saidaminov, G. Lakhwani, A. Rasmita, X. Liu, E. H. Sargent, W.
  Gao, *Nat. Rev. Mater.* 2020, *5*, 423.
- 25 [15] K. Leng, W. Fu, Y. Liu, M. Chhowalla, K. P. Loh, Nat. Rev. Mater. 2020, 1.
- 26 [16] C. R. Kagan, D. B. Mitzi, C. D. Dimitrakopoulos, *Science* 1999, 286, 945.
- [17] M. Yuan, L. N. Quan, R. Comin, G. Walters, R. Sabatini, O. Voznyy, S. Hoogland, Y. Zhao,
  E. M. Beauregard, P. Kanjanaboos, Z. Lu, D. H. Kim, E. H. Sargent, *Nat. Nanotechnol.* 2016, *11*, 872.
- [18] H. Tsai, W. Nie, J.-C. Blancon, C. C. Stoumpos, R. Asadpour, B. Harutyunyan, A. J.
  Neukirch, R. Verduzco, J. J. Crochet, S. Tretiak, others, *Nature* 2016, 536, 312.
- 32 [19] Z. Wang, Q. Lin, F. P. Chmiel, N. Sakai, L. M. Herz, H. J. Snaith, Nat. Energy 2017, 2, 1.
- [20] B. Zhao, S. Bai, V. Kim, R. Lamboll, R. Shivanna, F. Auras, J. M. Richter, L. Yang, L. Dai,
  M. Alsari, X.-J. She, L. Liang, J. Zhang, S. Lilliu, P. Gao, H. J. Snaith, J. Wang, N. C.
  Greenham, R. H. Friend, D. Di, *Nat. Photonics* 2018, *12*, 783.
- 36 [21] M. D. Smith, H. I. Karunadasa, Acc. Chem. Res. 2018, 51, 619.
- 37 [22] T. Luo, Y. Zhang, Z. Xu, T. Niu, J. Wen, J. Lu, S. Jin, S. (Frank) Liu, K. Zhao, *Adv. Mater.* 38 2019, *31*, 1903848.
- 39 [23] Q. Shang, Y. Wang, Y. Zhong, Y. Mi, L. Qin, Y. Zhao, X. Qiu, X. Liu, Q. Zhang, J. Phys.
   40 Chem. Lett. 2017, 8, 4431.
- [24] R. Quintero-Bermudez, A. Gold-Parker, A. H. Proppe, R. Munir, Z. Yang, S. O. Kelley, A.
  Amassian, M. F. Toney, E. H. Sargent, *Nat. Mater.* 2018, *17*, 900.
- 43 [25] G. Grancini, M. K. Nazeeruddin, Nat. Rev. Mater. 2019, 4, 4.
- 44 [26] C. C. Stoumpos, D. H. Cao, D. J. Clark, J. Young, J. M. Rondinelli, J. I. Jang, J. T. Hupp, M.
- 45 G. Kanatzidis, *Chem. Mater.* **2016**, *28*, 2852.

- [27] L. Mao, W. Ke, L. Pedesseau, Y. Wu, C. Katan, J. Even, M. R. Wasielewski, C. C. Stoumpos,
   M. G. Kanatzidis, J. Am. Chem. Soc. 2018, 140, 3775.
- 3 [28] A. Krishna, S. Gottis, M. K. Nazeeruddin, F. Sauvage, *Adv. Funct. Mater.* **2019**, *29*, 1806482.
- 4 [29] P. Huang, S. Kazim, M. Wang, S. Ahmad, ACS Energy Lett. 2019, 4, 2960.
- [30] Y.-K. Wang, D. Ma, F. Yuan, K. Singh, J. M. Pina, A. Johnston, Y. Dong, C. Zhou, B. Chen,
  B. Sun, H. Ebe, J. Fan, M.-J. Sun, Y. Gao, Z.-H. Lu, O. Voznyy, L.-S. Liao, E. H. Sargent, *Nat. Commun.* 2020, 11, 3674.
- 8 [31] M. Zhou, C. Fei, J. S. Sarmiento, H. Wang, Sol. RRL 2019, 3, 1800359.
- 9 [32] T. He, S. Li, Y. Jiang, C. Qin, M. Cui, L. Qiao, H. Xu, J. Yang, R. Long, H. Wang, M. Yuan,
   Nat. Commun. 2020, 11, 1672.
- 11 [33] Y. Han, S. Park, C. Kim, M. Lee, I. Hwang, Nanoscale 2019, 11, 3546.
- [34] H. Tsai, W. Nie, J.-C. Blancon, C. C. Stoumpos, R. Asadpour, B. Harutyunyan, A. J.
  Neukirch, R. Verduzco, J. J. Crochet, S. Tretiak, L. Pedesseau, J. Even, M. A. Alam, G.
  Gupta, J. Lou, P. M. Ajayan, M. J. Bedzyk, M. G. Kanatzidis, A. D. Mohite, *Nature* 2016, 536, 312.
- [35] N. R. Venkatesan, R. M. Kennard, R. A. DeCrescent, H. Nakayama, C. J. Dahlman, E. E.
   Perry, J. A. Schuller, M. L. Chabinyc, *Chem. Mater.* 2018, *30*, 8615.
- [36] Y. Lin, Y. Fang, J. Zhao, Y. Shao, S. J. Stuard, M. M. Nahid, H. Ade, Q. Wang, J. E. Shield,
   N. Zhou, A. M. Moran, J. Huang, *Nat. Commun.* 2019, *10*, 1008.
- [37] J.-C. Blancon, H. Tsai, W. Nie, C. C. Stoumpos, L. Pedesseau, C. Katan, M. Kepenekian, C.
  M. M. Soe, K. Appavoo, M. Y. Sfeir, S. Tretiak, P. M. Ajayan, M. G. Kanatzidis, J. Even, J.
  J. Crochet, A. D. Mohite, *Science* 2017, *355*, 1288.
- [38] M. Kepenekian, B. Traore, J.-C. Blancon, L. Pedesseau, H. Tsai, W. Nie, C. C. Stoumpos,
  M. G. Kanatzidis, J. Even, A. D. Mohite, S. Tretiak, C. Katan, *Nano Lett.* 2018, *18*, 5603.
- [39] A. Raja, L. Waldecker, J. Zipfel, Y. Cho, S. Brem, J. D. Ziegler, M. Kulig, T. Taniguchi, K.
  Watanabe, E. Malic, T. F. Heinz, T. C. Berkelbach, A. Chernikov, *Nat. Nanotechnol.* 2019, 14, 832.
- [40] L. Liu, Y. Bai, X. Zhang, Y. Shang, C. Wang, H. Wang, C. Zhu, C. Hu, J. Wu, H. Zhou, Y.
   Li, S. Yang, Z. Ning, Q. Chen, *Angew. Chem. Int. Ed.* 2020, *59*, 5979.
- [41] C. M. M. Soe, G. P. Nagabhushana, R. Shivaramaiah, H. Tsai, W. Nie, J.-C. Blancon, F.
  Melkonyan, D. H. Cao, B. Traoré, L. Pedesseau, M. Kepenekian, C. Katan, J. Even, T. J.
  Marks, A. Navrotsky, A. D. Mohite, C. C. Stoumpos, M. G. Kanatzidis, *Proc. Natl. Acad. Sci.* 2019, *116*, 58.
- [42] L. N. Quan, M. Yuan, R. Comin, O. Voznyy, E. M. Beauregard, S. Hoogland, A. Buin, A. R.
  Kirmani, K. Zhao, A. Amassian, D. H. Kim, E. H. Sargent, *J. Am. Chem. Soc.* 2016, *138*, 2649.
- [43] B. Song, J. Hou, H. Wang, S. Sidhik, J. Miao, H. Gu, H. Zhang, S. Liu, Z. Fakhraai, J. Even,
   *ACS Mater. Lett.* 2020, *3*, 148.
- 39 [44] Y. Zhao, H. Tan, H. Yuan, Z. Yang, J. Z. Fan, J. Kim, O. Voznyy, X. Gong, L. N. Quan, C.
  40 S. Tan, J. Hofkens, D. Yu, Q. Zhao, E. H. Sargent, *Nat. Commun.* 2018, *9*, 1607.
- [45] H.-J. Yen, P.-W. Liang, C.-C. Chueh, Z. Yang, A. K.-Y. Jen, H.-L. Wang, ACS Appl. Mater.
   *Interfaces* 2016, *8*, 14513.
- 43 [46] A. Z. Chen, M. Shiu, J. H. Ma, M. R. Alpert, D. Zhang, B. J. Foley, D.-M. Smilgies, S.-H.
  44 Lee, J. J. Choi, *Nat. Commun.* 2018, *9*, 1336.
- [47] J. Dong, S. Shao, S. Kahmann, A. J. Rommens, D. Hermida- Merino, G. H. ten Brink, M. A.
  Loi, G. Portale, *Adv. Funct. Mater.* 2020, *30*, 2001294.

- [48] F. Hao, C. C. Stoumpos, Z. Liu, R. P. H. Chang, M. G. Kanatzidis, J. Am. Chem. Soc. 2014, 136, 16411.
- [49] X. Zhang, X. Ren, B. Liu, R. Munir, X. Zhu, D. Yang, J. Li, Y. Liu, D.-M. Smilgies, R. Li,
  Z. Yang, T. Niu, X. Wang, A. Amassian, K. Zhao, S. (Frank) Liu, *Energy Environ. Sci.* 2017,
  10, 2095.
- [50] W. Nie, H. Tsai, J.-C. Blancon, F. Liu, C. C. Stoumpos, B. Traore, M. Kepenekian, O. Durand, C. Katan, S. Tretiak, *Adv. Mater.* 2018, *30*, 1703879.
- 8 [51] B.-E. Cohen, Y. Li, Q. Meng, L. Etgar, Nano Lett. 2019, 19, 2588.
- 9 [52] H. Li, X. Wang, T. Zhang, X. Gong, Q. Sun, H. Pan, Y. Shen, S. Ahmad, M. Wang, Adv.
   10 Funct. Mater. 2019, 29, 1903293.
- [53] T. Niu, H. Ren, B. Wu, Y. Xia, X. Xie, Y. Yang, X. Gao, Y. Chen, W. Huang, J. Phys. Chem.
   Lett. 2019, 10, 2349.
- [54] Y. Zheng, T. Niu, J. Qiu, L. Chao, B. Li, Y. Yang, Q. Li, C. Lin, X. Gao, C. Zhang, Y. Xia,
   Y. Chen, W. Huang, *Sol. RRL* 2019, *3*, 1900090.
- [55] F. Zhang, H. Lu, J. Tong, J. J. Berry, M. C. Beard, K. Zhu, *Energy Environ. Sci.* 2020, 13, 1154.
- [56] H. Tsai, R. Asadpour, J.-C. Blancon, C. C. Stoumpos, J. Even, P. M. Ajayan, M. G.
   Kanatzidis, M. A. Alam, A. D. Mohite, W. Nie, *Nat. Commun.* 2018, *9*, DOI 10.1038/s41467 018-04430-2.
- 20 [57] M. V. Khenkin, E. A. Katz, A. Abate, G. Bardizza, J. J. Berry, C. Brabec, F. Brunetti, V. 21 Bulović, Q. Burlingame, A. D. Carlo, R. Cheacharoen, Y.-B. Cheng, A. Colsmann, S. Cros, 22 K. Domanski, M. Dusza, C. J. Fell, S. R. Forrest, Y. Galagan, D. D. Girolamo, M. Grätzel, 23 A. Hagfeldt, E. von Hauff, H. Hoppe, J. Kettle, H. Köbler, M. S. Leite, S. (Frank) Liu, Y.-L. 24 Loo, J. M. Luther, C.-Q. Ma, M. Madsen, M. Manceau, M. Matheron, M. McGehee, R. 25 Meitzner, M. K. Nazeeruddin, A. F. Nogueira, C. Odabaşı, A. Osherov, N.-G. Park, M. O. 26 Reese, F. D. Rossi, M. Saliba, U. S. Schubert, H. J. Snaith, S. D. Stranks, W. Tress, P. A. 27 Troshin, V. Turkovic, S. Veenstra, I. Visoly-Fisher, A. Walsh, T. Watson, H. Xie, R. 28 Yıldırım, S. M. Zakeeruddin, K. Zhu, M. Lira-Cantu, Nat. Energy 2020, 5, 35.
- [58] Z. Jiang, X. Li, J. Strzalka, M. Sprung, T. Sun, A. R. Sandy, S. Narayanan, D. R. Lee, J.
   Wang, J. Synchrotron Radiat. 2012, 19, 627.
- 31